

Supplementary Information

Silicon carbide gated nanofluidic membrane for active control of electrokinetic ionic transport

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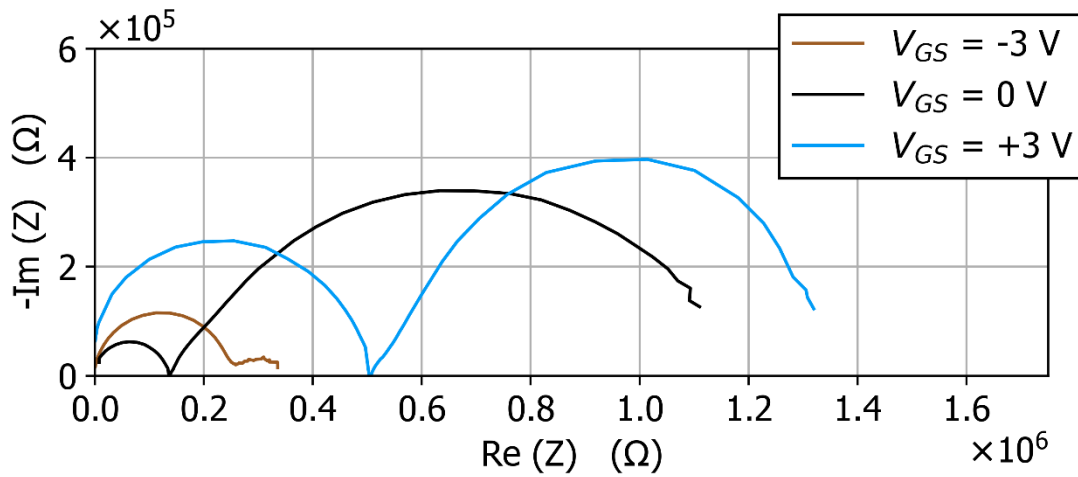


Figure S1. Impedance measurements presented as Nyquist plots performed on the a-SiC blank device recorded at different V_{GS} .